BCT4227

High-Speed DPDT Analog Switch

FEATURES

♦ V_{CC} Operating Range: 1.65V to 4.5V

♦ Rail-to-Rail Signal Range

♦ ON-Resistance Matching: 0.05 Ω (TYP)

♦ ON-Resistance Flatness: 0.08Ω (TYP)

♦ High Off Isolation: 58dB at 10MHz

♦ 54dB (10MHz) Crosstalk Rejection Reduces Signal Distortion

♦ Break-Before-Make Switching

♦ -3dB Bandwidth: 720MHz

♦ Extended Industrial Temperature Range: –40°C to 85°C

♦ Packaging (Pb-free & Green available)

GENERAL DESCRIPTION

The BCT4227 is a high bandwidth, fast double-pole double-throw (DPDT) analog switch. Its wide bandwidth and low bit-to-bit skew allow it to pass high-speed differential signals with good signal integrity. Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Industry-leading advantages include a propagation delay of less than 250ps, resulting from its low channel resistance and low I/O capacitance. Its high channel-to-channel crosstalk rejection results in minimal noise interference.

APPLICATIONS

Cell Phones

PDAs

Portable Instrumentation

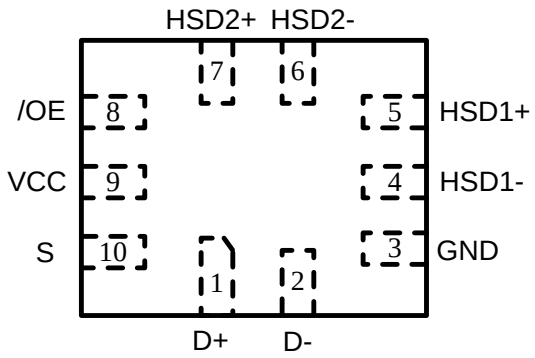
Differential Signal Data Routings

USB 2.0 Signal Routing

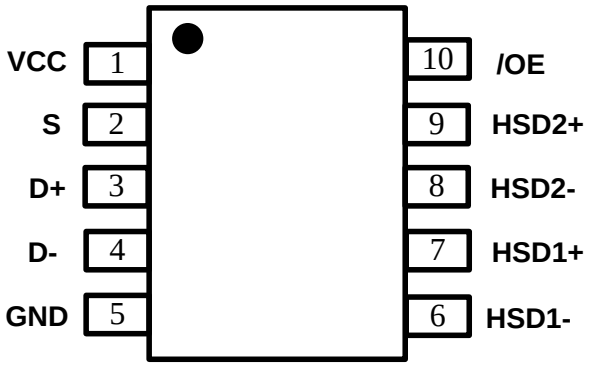
ORDERING INFORMATION

Ordering Code	Package Description	Temp Range	Top Marking
BCT4227ETB-TR	WQFN 1.4X1.8 -10	–40°C to +85°C	AMX
BCT4227EMB-TR	MSOP10	–40°C to +85°C	4227

PIN CONFIGURATION (Top View)



WQFN1.4*1.8-10



MSOP10

PIN DESCRIPTION

Pin Number	Name	Description
10	SEL	Select Input
3	GND	Ground
5 , 4	HSD1+, HSD1-	Data Ports 1
7 , 6	HSD2+,HSD2-	Data Ports 2
1 , 2	D+, D-	Data Ports
9	VCC	Positive Power Supply
8	/OE	Output Enable

LOGIC FUNCTION TABLE

/OE	SEL	HSD1+,HSD1-	HSD2+,HSD2-
1	X	OFF	OFF
0	0	ON	OFF
0	1	OFF	ON

MAXIMUM RATINGS

Symbol	Pins	Parameter	Value	Unit
V_{CC}	V_{CC}	Positive DC Supply Voltage	-0.5 to +5.25	V
V_{IS}	HSD1+, HSD1-, HSD2+, HSD2-	Analog Signal Voltage	-0.5 to V_{CC} +0.3	V
	D+, D-		-0.5 to +5.25	
V_{IN}	/OE	Control Input Voltage	-0.5 to +5.25	V
I_{CC}	V_{CC}	Positive DC Supply Current	50	mA
T_S		Storage Temperature	-65 to +150	°C
I_{IN}	/OE	Control Input Current	±20mA	mA

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability

ESD PROTECTION

Symbol	Parameter	Value	Unit
ESD	Human Body Model - All Pins	2.0	kV
ESD	Human Body Model - I/O to GND	8.0	kV

RECOMMENDED OPERATING CONDITIONS

Symbol	Pins	Parameter	Min	Max	Unit
V_{CC}		Positive DC Supply Voltage	1.65	4.5	V
V_{IS}	HSD1+, HSD1-, HSD2+, HSD2-	Analog Signal Voltage	GND	V_{CC}	V
	D+, D-		GND	4.2	
V_{IN}	/OE	Digital Select Input Voltage	GND	V_{CC}	V
T_A		Operating Temperature Range	-40	+85	°C

Minimum and maximum values are guaranteed through test or design across the Recommended Operating Conditions, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

DC ELECTRICAL CHARACTERISTICS (Typical: T = 25°C)

BCT4227 SUPPLY AND LEAKAGE CURRENT

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
I_{CC}	V_{CC}	Quiescent Supply Current	V_{IS} = V_{CC} or GND; I_{OUT} = 0 A	1.65 -4.5	-	-	1.0	uA
I_{CCT}	V_{CC}	Increase in I_{CC} per Control Voltage	V_{IN} = 2.6 V	3.6	-	-	10	uA
I_{OZ}	HSD1+, HSD1-, HSD2+, HSD2-	OFF State Leakage Current	0 ≤ V_{IS} ≤V_{CC}	1.65 - 4.5	-	-	±1.0	uA
I_{OFF}	D+, D-	Power OFF Leakage Current	0 ≤ V_{IS} ≤4.5 V	0	-	-	±1.0	uA

BCT4227 DIGITAL INPUT VOLTAGE

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
V_{IH}	S,/OE	Input High Voltage		3.6	1.6	-	-	V
V_{IL}	S,/OE	Input Low Voltage		3.6	-	-	0.5	V

BCT4227 HIGH SPEED ON RESISTANCE

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
R_{ON}		On-Resistance	V_{IS} = 0 V to 0.4 V, I_{ON} = 8 mA	2.7 3.3 4.2		9.0 8.0 7.0	12 10 8.0	Ω
R_{FLAT}		On-Resistance Flatness	V_{IS} = 0 V to 0.4 V, I_{ON} = 8 mA	2.7 3.3 4.2		1.6 1.5 1.4		Ω
R_{ON}		On-Resistance Matching	V_{IS} = 0 V to 0.4 V, I_{ON} =8 mA	2.7 3.3 4.2		1.6 1.5 1.4		Ω

BCT4227 DC ELECTRICAL CHARACTERISTICS

(continued) FULL SPEED ON RESISTANCE (Typical: T = 25°C, V_{CC} = 3.3 V)

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
R_{ON}		On-Resistance	V_{IS} = 0 V to V_{CC}, I_{ON} = 8 mA	2.7 3.3 4.2		9.0 8.5 7.5	12 10.5 8.5	Ω
R_{FLAT}		On-Resistance Flatness	V_{IS} = 0 V to V_{CC}, I_{ON} = 8 mA	2.7 3.3 4.2		1.6 1.5 1.4		Ω
R_{ON}		On-Resistance Matching	V_{IS} = 0 V to V_{CC}, I_{ON} = 8 mA	2.7 3.3 4.2		2.20 2.45 2.65		Ω

BCT4227 AC ELECTRICAL CHARACTERISTICS

TIMING/FREQUENCY (Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50Ω , C_L = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
t_{ON}	Closed to Open	Turn-ON Time	See test circuit 2	1.65 - 4.5		14	30	ns
t_{OFF}	Open to Closed	Turn-OFF Time	See test circuit 2	1.65 - 4.5		10	20	ns
t_{BBM}		Break-Before-Make Delay	See test circuit 1	1.65 - 4.5	3.0	4.4	7.0	ns
BW		-3 dB Bandwidth	C_L = 5 pF	1.65 - 4.5		650		MHz
			C_L = 0 pF			720		

BCT4227 ISOLATION

(Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50Ω, C_L = 5 pF)

Symbol	Pins	Parameter	Test Conditions	V_{CC} (V)	-40°C to +85°C			Unit
					Min	Typ	Max	
OIRR	Open	OFF-Isolation	f = 10 MHz	1.65 - 4.5		-58		dB
XTALK	HSD1+ to HSD1-	Non-Adjacent Channel Crosstalk	f = 10 MHz	1.65 - 4.5		-54		dB

BCT4227 CAPACITANCE

(Typical: T = 25°C, V_{CC} = 3.3 V, R_L = 50Ω , C_L = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	-40°C to +85°C			Unit
				Min	Typ	Max	
C_{IN}	OE	Control Pin Input Capacitance	V_{CC} = 0 V	-	3.0	-	pF
C_{ON}	D+ to HSD1+ or HSD2+	ON Capacitance	V_{CC} = 3.3 V; OE = 0 V	-	8.0	-	pF
C_{OFF}	HSD2+, HSD2-	OFF Capacitance	V_{CC} = V_{IS} = 3.3 V; OE = 3.3 V	-	4.5	-	pF

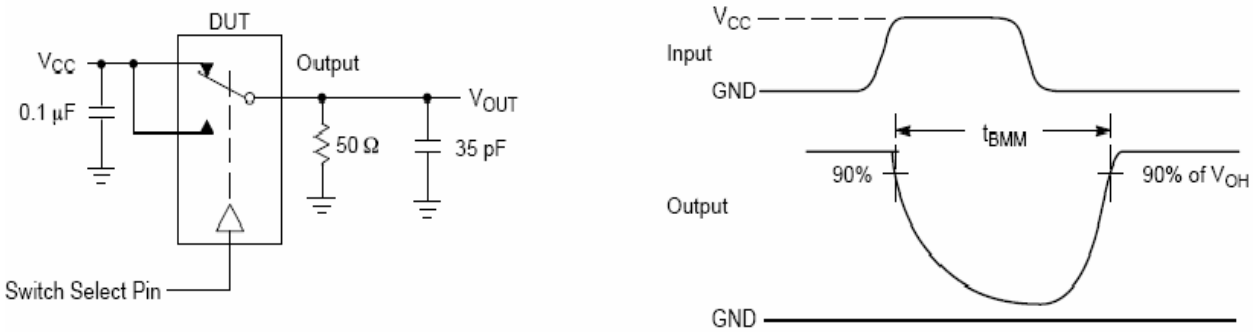


Figure 1. t_{BBM} (Time Break-Before-Make)

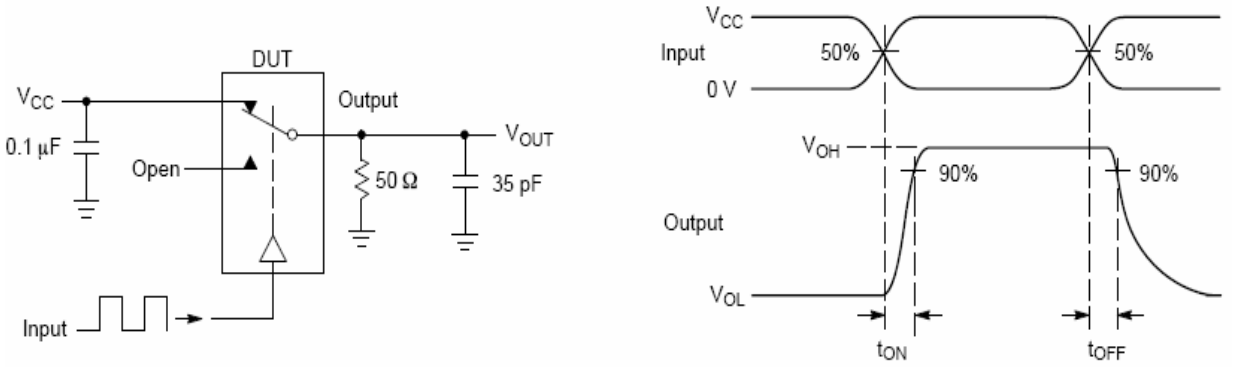


Figure 2. t_{ON} / t_{OFF}

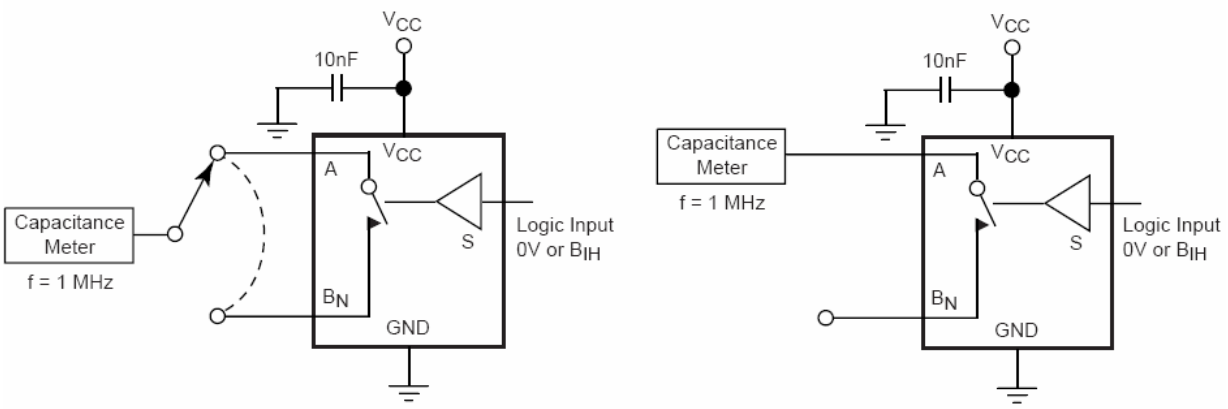


Figure 3. Channel ON/OFF Capacitance

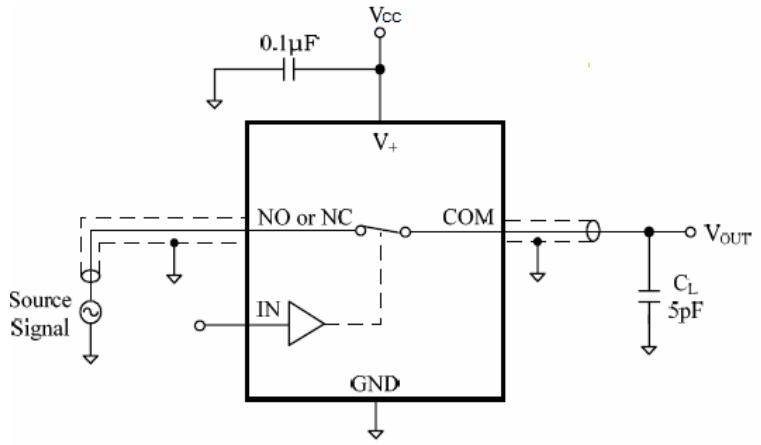


Figure 4. Bandwidth -3dB

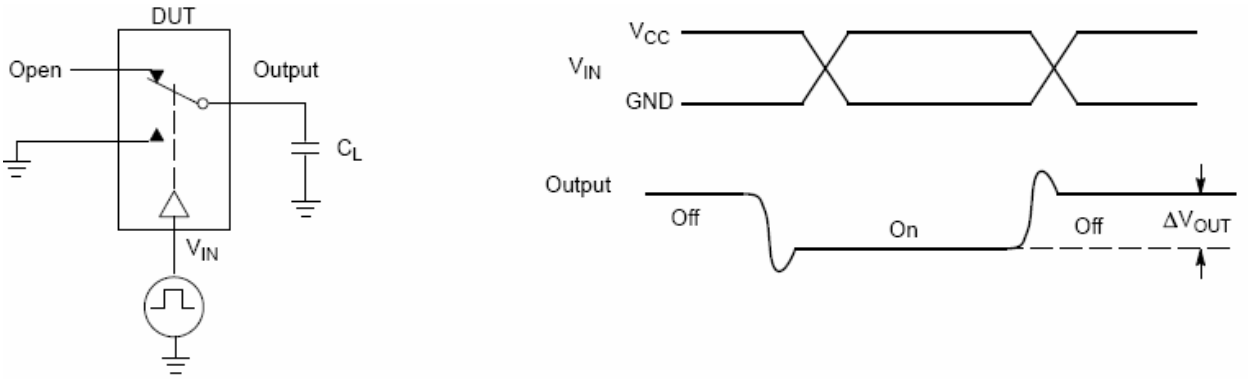


Figure 5. Charge Injecting (Q)

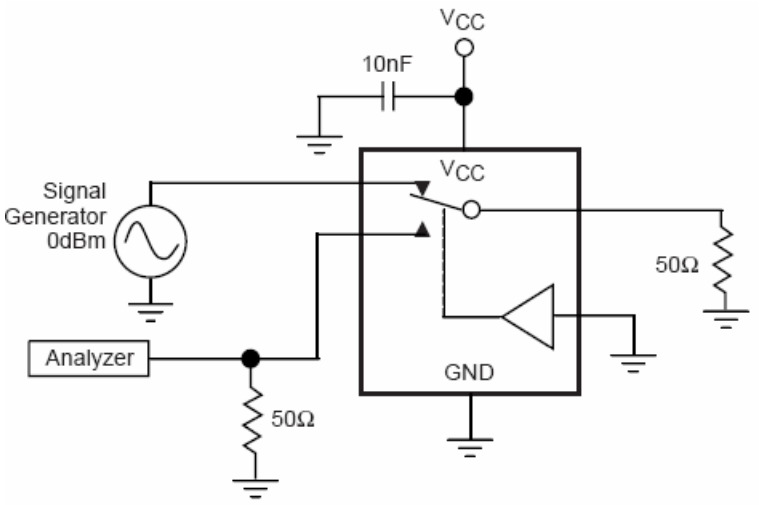
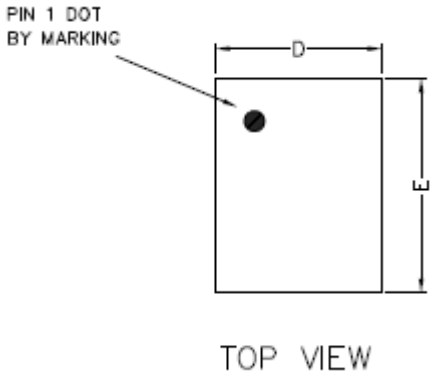


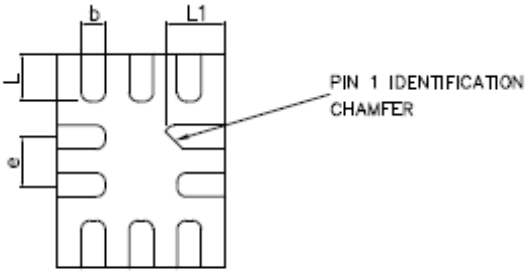
Figure 6. Crosstalk

Package Information

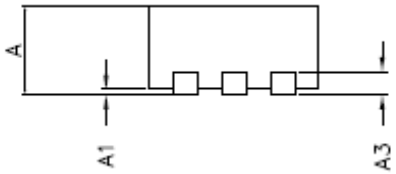
WQFN 1.4X1.8 -10



TOP VIEW



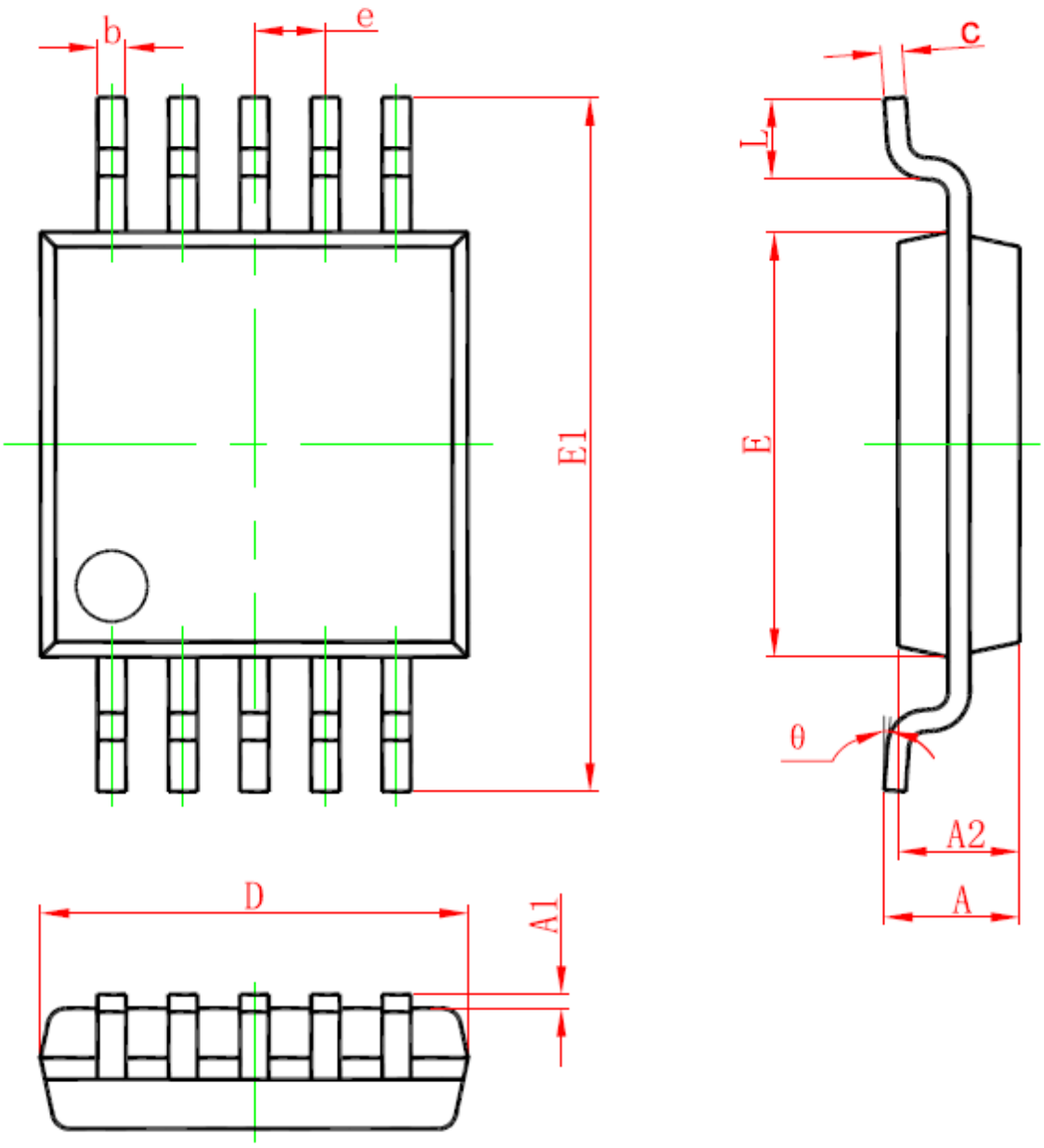
BOTTOM VIEW



COMMON DIMENSIONS(MM)			
PKG.	UT: ULTRA THIN		
REF.	MIN.	NOM.	MAX
A	0.50	0.55	0.60
A1	0.00	–	0.05
A3	0.15 REF.		
D	1.35	1.40	1.45
E	1.75	1.80	1.85
b	0.15	0.20	0.25
L	0.30	0.40	0.50
L1	0.40	0.50	0.60
e	0.40 BSC		

Package Information

MSOP10



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.180	0.280	0.007	0.011
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
e	0.50(BSC)		0.020(BSC)	
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°